

Date:- 10 Oct, 2003

Data Sheet_Issue:- 1

Provisional Data

Extra Fast Recovery Diode

Type F0900V#520

Development Type No.: FX055VC52

Absolute Maximum Ratings

	VOLTAGE RATINGS)	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	$\overline{}$	/	5200	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)		/	5300	V

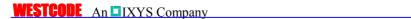
	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} =55°C, (note 2)	816	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =86°C, (hote 2)	514	Α
$I_{F(AV)M}$	Maximum average forward. T _{sink} =85°C, (hote 3)	312	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°0 (note 2)	1654	Α
$I_{f(d.c.)}$	D.C. forward current, T _{sink} =25°C, (pote 4)	1452	Α
I _{FSM}	Peak non-repetitive surge t _p =10n(s, VRM=0.6VRRM, (note 5)	10.45	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{RM} ≤10V, (note 5)	11.5	kA
l ² t	I^2 t capacity for fusing $t_p=10$ ms, $V_{RM}=0.6V_{RRM}$, (note 5)	546×10 ³	A^2s
l ² t	I ² t capacity for fusing t _p =10ms, V _{RM} ≤10V, (note 5)	661×10 ³	A ² s
Тј ор	Operating temperature range	-40 to +115	°C
T _{stg}	Storage temperature range ()	-40 to +150	°C
			1

Notes:-

- De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
 Double side cooled, single phase; 80Hz, 180° half-sinewave.
 Single side cooled, single phase, 50Hz, 180° half-sinewave.

- Double side cooled.
- 5) Half-sinewaye, 1/15 6 T_i initial
- Current (I_F) latings have been calculated using V_{T0} and r_T (see page 2).





Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	3.20	I _{FM} =900A	V
▼ FIVI	maximum peak forward voltage	-	-	4.40	I _{FM} =1800A	
V_{T0}	Threshold voltage	-	-	2.024		V
r _T	Slope resistance	-	-	1.274	Current range 816A-2448A (Note 2)	mΩ
V _{T0}	Threshold voltage	-	-	2.084		V
r _T	Slope resistance	-	-	1.234	Current range 900A 2700A	mΩ
V _{FRM}	Maximum forward recovery voltage	-	-	155	di/dt = 1000A/us	V
VFRM	waximum forward recovery voltage	-	-	110	di/dt = 1000A(µs, T _j =25°C	V
loou	Peak reverse current	-	-	296	Rated VRRM	mA
IRRM	reak reverse current	-	-	2004	Rated V _{RRM} , T = 25°C	111/4
Q _{ra}	Recovered charge, 50% Chord	-	2000	-	N _M =909A, t ₀ =1000μs, di/dt=2000A/μs,	μC
t _{rr}	Reverse recovery time, 50% Chord	-	1.4	-	V _r =409V, 50% Chord. (note 3)	μs
I _{rm}	Reverse recovery current	-	3000	-	Vi 1000, 00 / 010/d. (note 0)	Α
Q _{ra}	Recovered charge, 50% Chord	-	230	350		μC
t _{rr}	Reverse recovery time, 50% Chord	-	3,8 (7//	I _{FM} =1000A, t _p =1000μs, di/dt=60A/μs,	μs
I _{rm}	Reverse recovery current	-	120	(L)	V₁=50V, 50% Chord.	Α
R_{thJK}	Thermal resistance, junction to heatsink	- /		0.016	Double side cooled	K/W
-thJK	memai resistance, junction to neatsink	- ((- {	0.032	Single side cooled	1000
F	Mounting force	27		34		kN
W_t	Weight		1000	-		g

Notes:-

- Unless otherwise indicated T_j=115°C
 V_{T0} and r_T were used to calculate the current ratings illustrated on page one.
 Figures 3-7 were compiled using these conditions.
- 4) For other clamp forces consult factory.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{RRM} (V)	V _{RSM} (V)	V _R dc
52	5200	5300	(2/24/0/) ~/
			\wedge

2.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for 1 below 25°C.

3.0 ABCD Constants

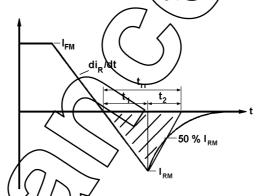
These constants (applicable only over current range of V_F characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

where I_F = instantaneous forward current.

4.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. (a) below



(ii) Q_{rr} is based on a 150μs integration time.

I.e.
$$Q_{rr} = \int_{0}^{150 \, \mu s} i_{rr}.dt$$

$$K \ Factor = \frac{t_1}{t_2}$$



5.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot \left[k + f \cdot R_{th(JK)}\right]$$

Where $k = 0.2314 \, (^{\circ}C/W)/s$

E = Area under reverse loss waveform per pulse in joyles (W.s.)

f = Rated frequency in Hz at the original sink temperature.

 $R_{th(J-Hs)}$ = d.c. thermal resistance (°C/W)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

NOTE 1 - Reverse Recovery Loss by Measuremen



- (a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.
- (b) A suitable, polarised, clipping citculit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.
- (c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot \frac{di}{dt}}$$

Where: $V_r = Commutating source voltage$

C_S = Snubber capacitance R = Snubber resistance

6.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor of excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

7.0 Computer Modelling Parameters

7.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_o + \sqrt{V_o + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s}$$

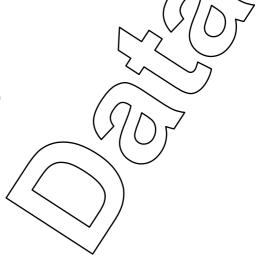
Where $V_{T0} = 2.024 \text{V}$, $r_T = 1.274 \text{m}\Omega$

ff = form factor (normally unity for fast diode applications)

$$W_{_{AV}} = \frac{\Delta T}{R_{_{th}}}$$

$$\Delta T = T_{j(MAX)} - T_K$$

7.2 Calculation of V_F using ABCD Coefficients



The forward characteristic I_F Vs V_F, on page 6 is represented in two ways;

- (i) the well established V_0 and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + O \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for hot characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients	115°C Coefficients
-0.70095013	0.263206271
B / 0.55/16109	0.133148
C 7/638×10 ⁻⁴	5.18755×10 ⁻⁴
3.5077×10 ⁻⁴	0.05197278

8.0 Frequency Ratings

The curves illustrated in figures 8 to 16 are for guidance only and are superseded by the maximum ratings shown on page 1

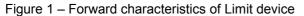
9.0 Square wave ratings

These ratings are given for load component rate of rise of forward current of 100 and 500 A/us.

10.0 Duty cycle lines

The 100% duty cycle is represented on all the ratings by a straight line. Other duties can be included as parallel to the first.

Curves



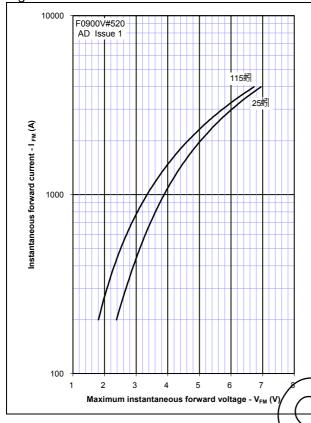
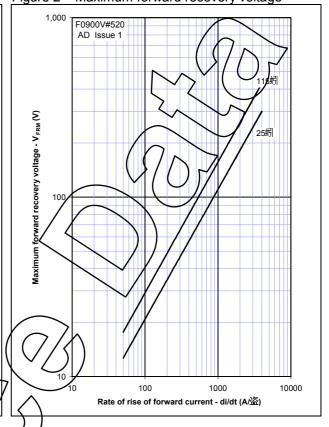


Figure 2 – Maximum forward recovery voltage



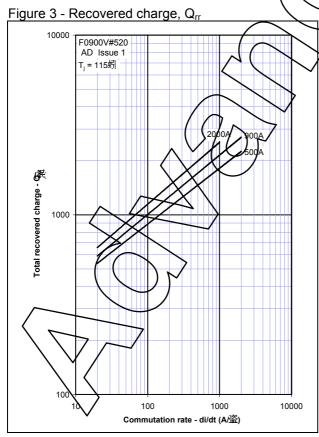
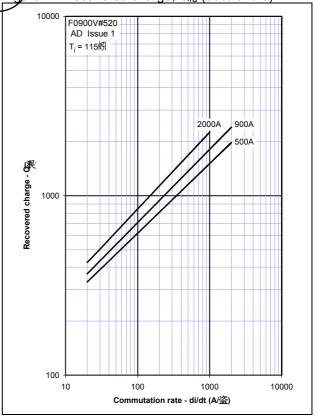


Figure 4 - Recovered charge, Q_{ra} (50% chord)



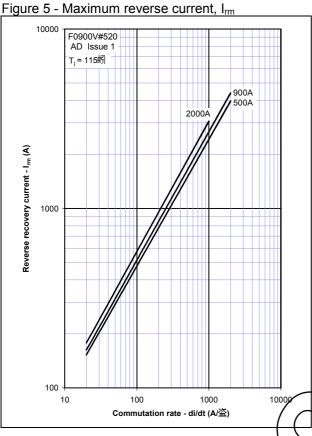
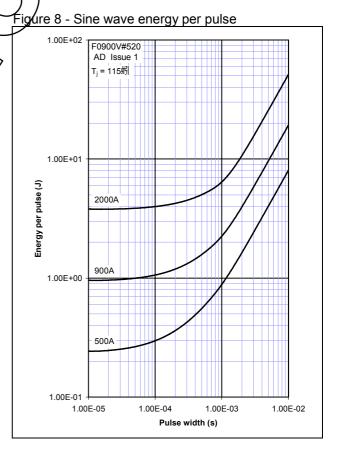


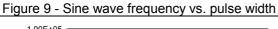
Figure 6 - Maximum recovery time, t_{rr} (50% chord) 0900V#520 2000A 900A 1000 10000

100

Commutation rate - di/dt (A/盗)

Figure 7 - Reverse recovery energy per pulse F0900V#520 AD Issue 1 T_i = 115蚓 V_R = 400V No Snubber Energy per pulse - E, (J) 1000 100 1000 10000 Commutation rate - di/dt (A/盗)





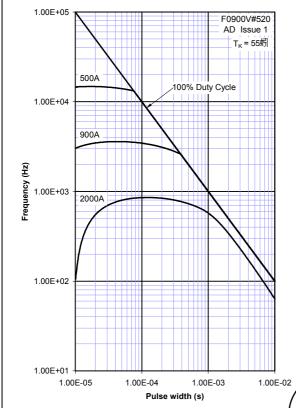


Figure 10 - Sine wave frequency vs. pulse width

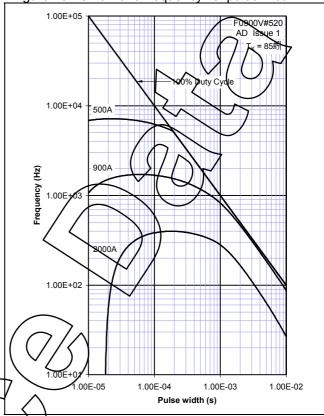


Figure 11 - Square wave energy per pulse

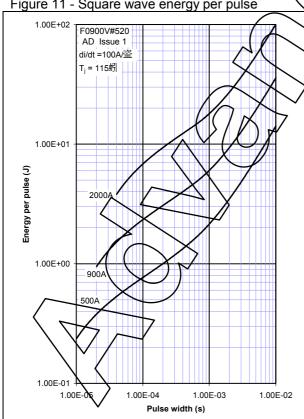


Figure 12 - Square wave energy per pulse

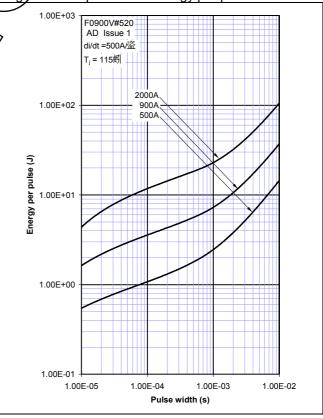


Figure 13 - Square wave frequency vs. pulse width

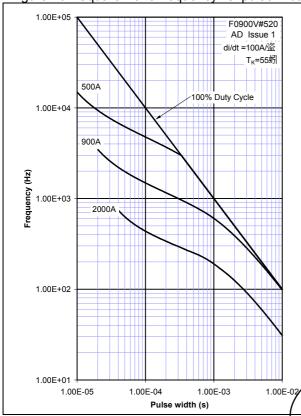
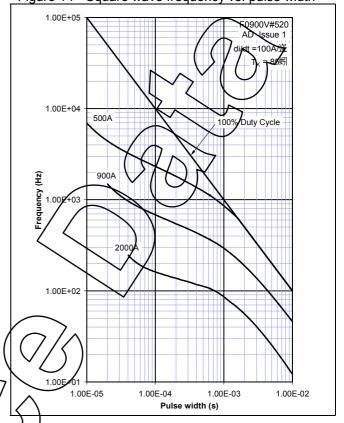


Figure 14 - Square wave frequency vs. pulse width



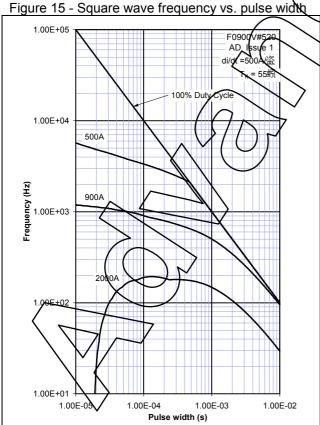
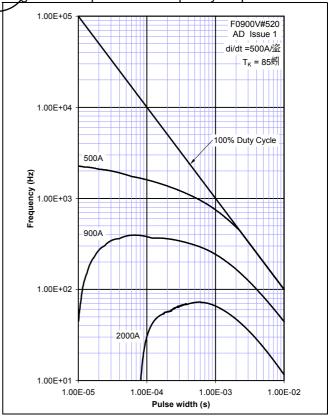
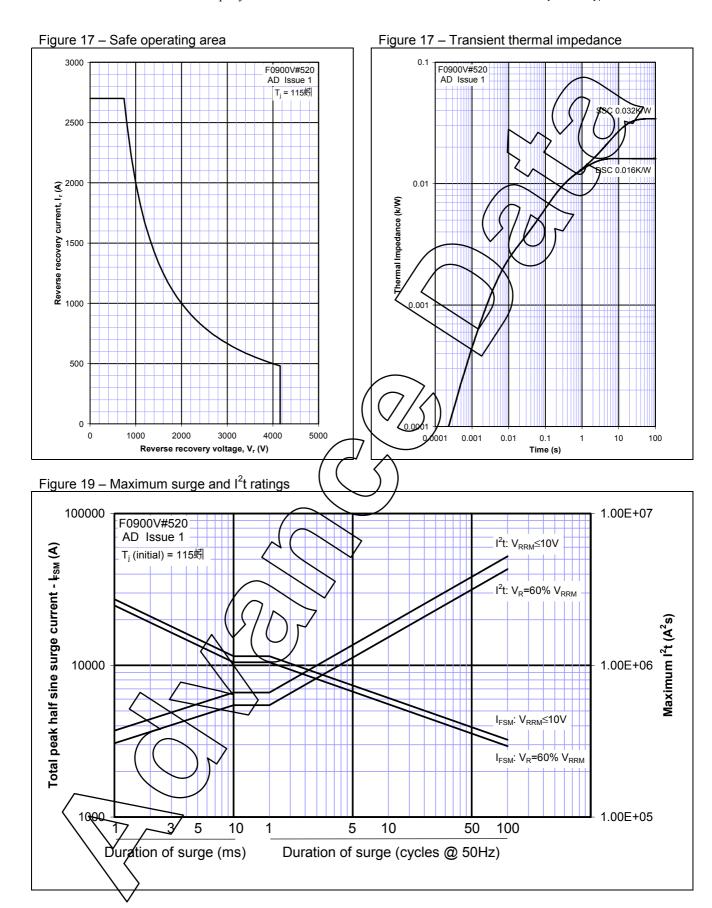


Figure 16 - Square wave frequency vs. pulse width





Outline Drawing & Ordering Information

